



# **MMBT123S**

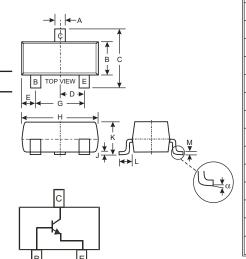
### 1A NPN SURFACE MOUNT TRANSISTOR

#### **Features**

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- High Collector Current Rating
- Suitable as a low voltage high current driver
- Lead Free/RoHS Compliant (Note 2)

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking (See Page 2): K6D
- Ordering & Date Code Information: See Page 2
- Weight: 0.008 grams (approximate)



SOT-23									
Dim	Dim Min Max								
Α	0.37	0.51							
В	1.20	1.40							
С	2.30	2.50							
D	0.89	1.03							
Е	0.45	0.60							
G	1.78	2.05							
Н	2.80	3.00							
J	0.013	0.10							
K	0.903	1.10							
L	0.45	0.61							
M	0.085	0.180							
α	0°	8°							
All Dimensions in mm									

### **Maximum Ratings** @ $T_A = 25$ °C unless otherwise specified

Characteristic	Symbol	MMBT123S	Unit
Collector-Base Voltage	V <sub>CBO</sub>	45	V
Collector-Emitter Voltage	V <sub>CEO</sub>	18	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current - Continuous	Ic	1	А
Power Dissipation (Note 1)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	417	°C/W
Operating and Storage and Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.



## Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 3)								
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	45	_	V	$I_C = 100 \mu A, I_E = 0$			
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	18	_	V	$I_C = 1 \text{mA}, I_B = 0$			
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5	_	V	$I_E = 100 \mu A, I_C = 0$			
Collector Cutoff Current	I <sub>CBO</sub>	_	1	μА	$V_{CB} = 40V, I_{E} = 0$			
Emitter Cutoff Current	I <sub>EBO</sub> — 1		μА	$V_{EB} = 4V, I_{C} = 0$				
ON CHARACTERISTICS (Note 3)								
DC Current Gain	h <sub>FE</sub>	150	800	_	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1V			
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.5	V	I <sub>C</sub> = 300mA, I <sub>B</sub> = 30mA			
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	C <sub>obo</sub>	_	8	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0			
Current Gain-Bandwidth Product	f⊤	100	_	MHz	V <sub>CB</sub> = 10V, I <sub>E</sub> = 50mA, f = 100MHz			

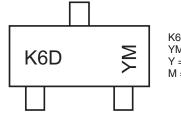
Notes: 3. Short duration pulse test used to minimize self-heating effect.

## Ordering Information (Note 4)

Device	Packaging	Shipping
MMBT123S-7-F	SOT-23	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



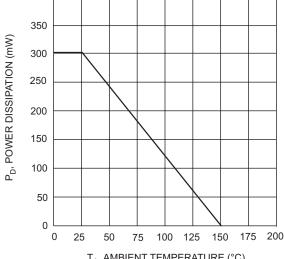
K6D = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Code N P R S T U V W	Year	2002	2003	2004	2005	2006	2007	2008	2009
	Code	N	Р	R	S	Т	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs **Ambient Temperature** 

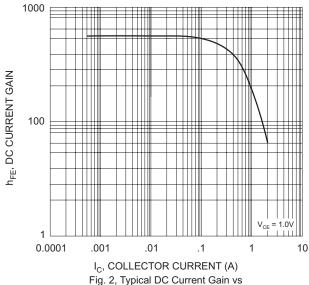


Fig. 2, Typical DC Current Gain vs Collector Current

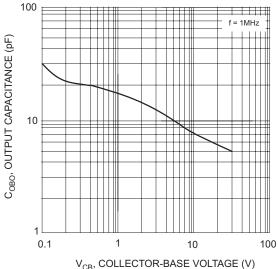
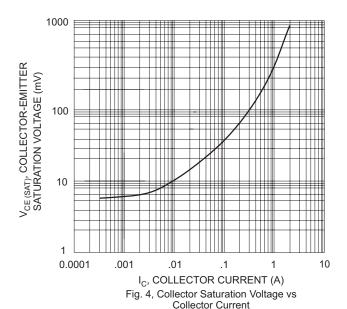


Fig. 3, Output Capacitance vs. Collector-Base Voltage



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